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July 2016

FL77905

Analog / PWM / Phase-cut Dimmable Compact LED Direct AC Driver

Features

- The simplest Direct AC LED Driver with Only Two External RC Passive Components
- Wide AC Input Range : 90~305 V_{AC}
- Three Integrated High-Voltage LED Constant Current Sinks of up to 75 mA (RMS) Capability
- TRIAC Dimmable (Leading/Trailing Edge)
- Rheostat Dimmable
- Analog/Digital PWM Dimming Function
- High Power Factor (above 0.98 in normal configuration)
- Adjustable LED Power with an External Current Sense Resistor
- Low Harmonic Content (THD under 20% in Normal Configuration)
- Compact SOIC 8-Lead Package
- Flexible LED Forward Voltage Configuration
- Power Scalability with Multiple Driver ICs
- Over-Temperature Protection (OTP)

Applications

- General LED Driving Solution for Residential, Commercial and Industrial Lighting

Description

The FL77905 is a direct AC line LED driver with minimal number of external RC passive components. In normal configuration, one resistor is to adjust LED power, and one capacitor is to provide a stable voltage to an internal biasing shunt regulator.

The FL77905 provides phase-cut dimming with wide dimming range, smooth dimming control and good dimmer compatibility. It achieves high efficiency with high PF and low THD which makes the FL77905 suitable for high-efficiency LED lighting systems. The FL77905 can also be used with a rheostat dimmer switches which are suitable for desktop or indoor lamps.

The FL77905 has a dedicated DIM pin which is designed to be used with analog or digital PWM dimming.

Operation of FL77905 admits driving higher-wattage systems, such as street lights and down lights, by simply parallel connecting the driver ICs.

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FL77905MX	-40 to 125°C	8-Lead, Small Outline Integrated Circuit (SOIC) JEDEC MS012 150” Narrow Body, Exposed Pad	2,500 per Reel

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Typical Application

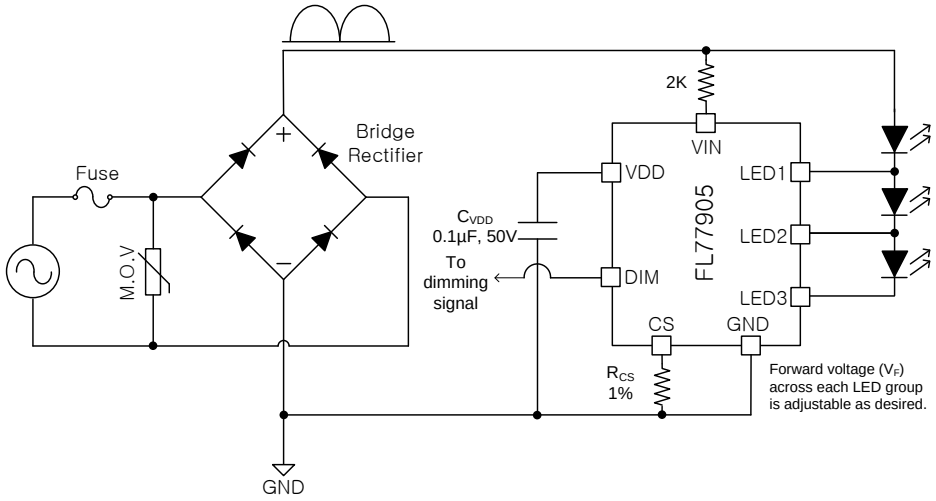


Figure 1. Typical Application Schematic

Block Diagram

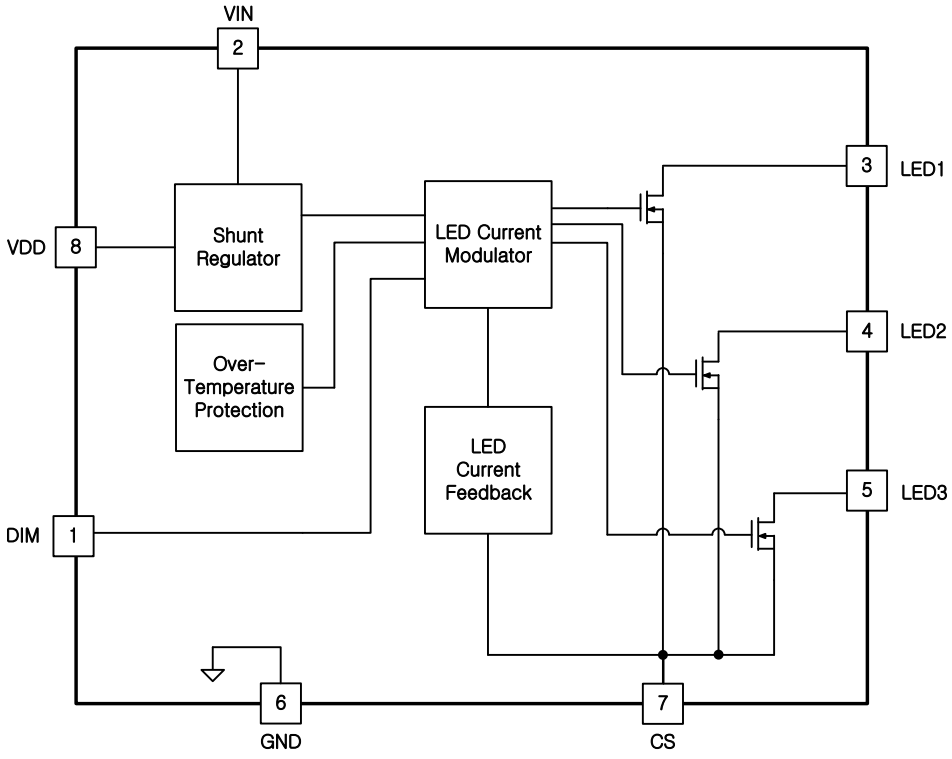


Figure 1. Simplified Block Diagram

Pin Configuration

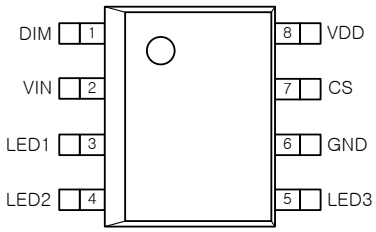


Figure 2. Pin Configuration (Top View)

Thermal Characteristics [1] [2]

Component	Package	Θ_{JA} (1S PCB)	Θ_{JA} (2S2P PCB)	Unit
FL77905MX	8-Lead, Small Outline Integrated Circuit (SOIC) JEDEC MS012 150" Narrow Body, Exposed Pad	156	37	°C/W

Notes:

1. Θ_{JA}: Thermal resistance between junction and ambient, dependent on the PCB design, heat sinking, and airflow. The value given is for natural convection with no heatsink using the 1S and 2S2P boards, as specified in JEDEC standards JESD51-2, JESD51-5, and JESD51-7, as appropriate.
2. Junction-to-air thermal resistance is highly dependent on application and PCB layout. In application where the device dissipates high levels of power during operation, special care of thermal dissipation issues in PCB design must be taken.

Pin Definitions

Pin#	Name	Description
1	DIM	**Dimming Signal Input Pin**. This pin is used to further adjust LED current of a given R_{CS} value. Apply 0 V to 5 V as the DIM signal. Both analog and digital PWM signal can be used.
2	VIN	**Rectified AC Input Voltage**. Connect this pin to rectified AC voltage after a bridge rectifier.
3	LED1	**LED String Cathodes**. Connect cathode(s) of each LED group to these pins.
4	LED2	
5	LED3	
6	GND	**Ground Reference Pin**. Tie this pin directly to local ground plane. This ground should not be tied to earth ground because it is not isolated from AC mains.
7	CS	**LED Current Sense Pin**. Limits the LED current depending on voltage across sensing resistor. The CS pin is used to set the LED current regulation target.
8	VDD	**Internal Biasing Shunt Regulator Output**. Voltage on this pin supplies internal circuitry of FL77905. A 17-V shunt regulator is internally connected to this pin. A bypassing capacitor is recommended to be added to reduce noise from VIN.
0	EP	**Exposed Thermal Pad**. EP is not tied to GND inside the IC. It is recommended to tie it to GND externally.

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{IN}	VIN Voltage	-0.3	500.0	V
V_{LED1}	LED1 Pin Voltage	-0.3	500.0	V
V_{LED2}	LED2 Pin Voltage	-0.3	500.0	V
V_{LED3}	LED3 Pin Voltage	-0.3	200.0	V
V_{CS}	CS Pin Voltage	-0.3	6.0	V
V_{DIM}	DIM Pin Voltage	-0.3	6.0	V
T_J	Junction Temperature	-55	+150	ºC
T_{STG}	Storage Temperature	-65	+150	ºC
I_{LED1}	LED1 Current		80	mA
I_{LED2}	LED2 Current		100	mA
I_{LED3}	LED3 Current		150	mA

Notes:

3. Stress beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.
4. All voltage values, except differential voltages, are given with respect to the GND pin.
5. Human Body Model, ANSI/ESDA/JEDEC JS-001-2012: 1.0 kV at Pins 2~4, 0.4 kV at Pin 5, 1.5 kV at Pins 1, 7~8.
6. Charged Device Model, JESD22-C101: 1.0 kV at Pins 1~8.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
T_J	Operating Junction Temperature	-40	+125	°C

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Electrical Characteristics

Unless otherwise noted, R_{CS} = 10 Ω, T_A = 25°C. Currents are defined as positive into the device and negative out of the device.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
VIN Supply						
$I_{QUIES.VIN}$	VIN Quiescent Current	V_{IN} = 500 V Max.		0.75	1.20	mA
VDD Output						
V_{DD}	VDD Voltage	V_{IN} = 20.0 V	16	17	18	V
LED Current						
I_{LED1}	LED1 Current	V_{IN} = 20.0 V, V_{LED1} = 20.0 V	40.4	47.0	53.6	mA
I_{LED2}	LED2 Current	V_{IN} = 20.0 V, V_{LED2} = 35.0 V	78.2	86.0	93.8	mA
I_{LED3}	LED3 Current	V_{IN} = 20.0 V, V_{LED3} = 20.0 V	87.8	96.0	104.2	mA
Over-Temperature Protection						
T_{OTP}	OTP Temperature(7)			170		°C
Leakage Current						
$I_{LED1-LK}$	LED1 Leakage Current	V_{LED1} = 500 V, V_{IN} = 0 V			1	µA
$I_{LED2-LK}$	LED2 Leakage Current	V_{LED2} = 500 V, V_{IN} = 0 V			1	µA
$I_{LED3-LK}$	LED3 Leakage Current	V_{LED3} = 200 V, V_{IN} = 0 V			1	µA

Note:

7. Not tested in production. Internal over-temperature protection circuitry protects the device from permanent damage. LEDs shut down at the junction temperature of T_J=170°C (typical).

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Typical Performance Characteristics

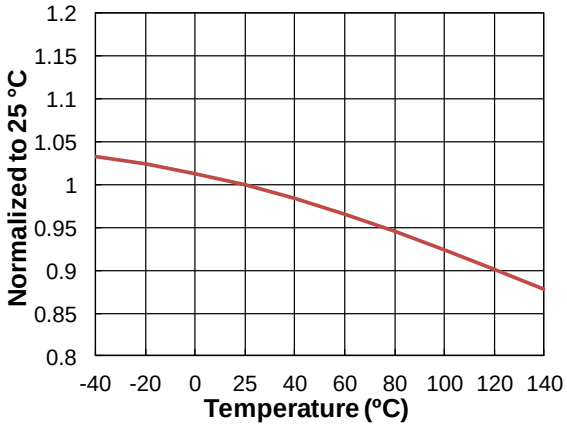


Figure 3. $I_{QUIES.VIN}$ vs. Temperature

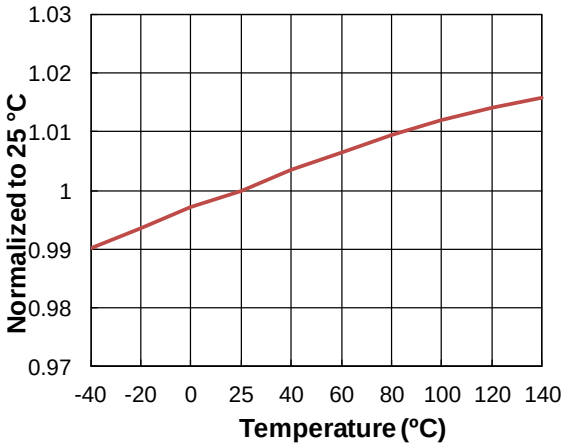


Figure 4. V_{DD} vs. Temperature

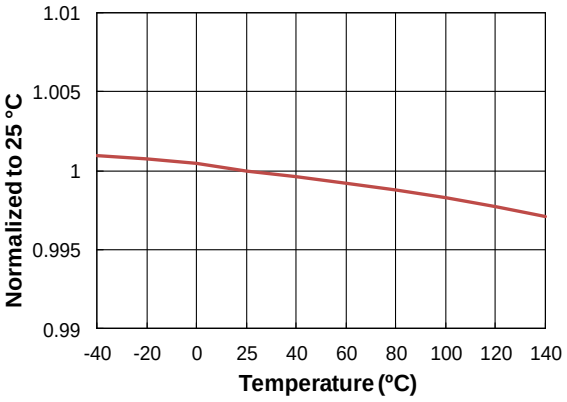


Figure 5. I_{LED1} vs. Temperature

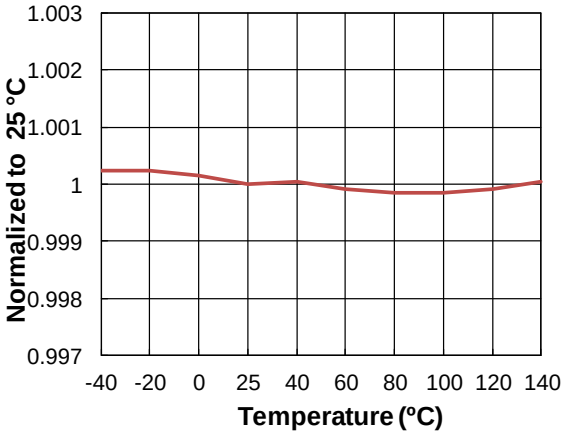


Figure 6. I_{LED2} vs. Temperature

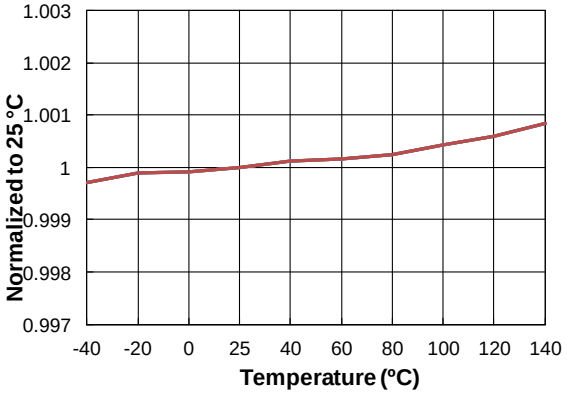


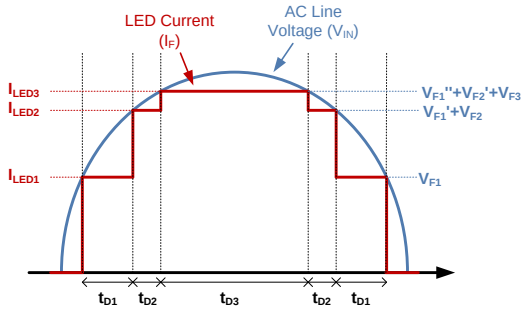
Figure 7. I_{LED3} vs. Temperature

Functional Description

The FL77905 can drive LED strings attached directly to the rectified AC mains using only two external RC components (R_{CS} and C_{VDD}). With three integrated high voltage current sink, LED current in each string is precisely controlled with system compactness. High PF and low THD are obtained by the optimized current sink levels. Phase-cut dimming is easily obtained with wide dimming range and good dimmer compatibility. Dedicated DIM pin is used to implement analog or digital dimming function. Flicker index in the direct AC drive topology can be improved by adopting proprietary self valley-fill solution.

Operation

When the rectified AC line voltage, V_{IN}, is higher than the forward voltage of the consecutive LED groups, each LED group turns on automatically as the corresponding current sink has enough voltage headroom across it. Each current sink increases up to the predefined current level and maintains that level until the following channel's current sink gets enough voltage headroom across it.



- t_{D1}: Current is directed to LED1 pin through 1st LED group.
- t_{D2}: Current is directed to LED2 pin through 1st and 2nd LED groups.
- t_{D3}: Current is directed to LED3 pin through 1st, 2nd, and 3rd LED groups.
- $V_{F1}/V_{F1}'/V_{F1}''$: Forward voltage at forward current of $I_{LED1}/I_{LED2}/I_{LED3}$ in 1st LED group.
- V_{F2}/V_{F2}': Forward voltage at forward current of I_{LED2}/I_{LED3} in 2nd LED group.
- V_{F3}: Forward voltage at forward current of I_{LED3} in 3rd LED group.

Figure 8. FL77905 Operation

When V_{IN} reaches to the forward voltage across the 1st LED group (V_{F1}) at forward current $I_F = I_{LED1}$, the current drawn from the V_{IN} is directed to the LED1 through the 1st LED group. In sequence, when V_{IN} reaches forward voltage across 1st and 2nd LED groups ($V_{F1}'+V_{F2}$) at $I_F = I_{LED2}$, the current is directed to LED2 across 1st and 2nd LED groups. Finally, when V_{IN} reaches $V_{F1}''+V_{F2}'+V_{F3}$ at $I_F=I_{LED3}$, the LED current goes through 1st, 2nd, and 3rd LED groups and sinks to the LED3.

Whenever the active channel (one that is sinking LED current) is changed from one channel to the adjacent channel with respect to the change in the V_{IN}, the new active channel's current increases gradually while the existing active channel's current decreases at the same time. This smooth current transition reduces frequency harmonic contents and improves power factor as well as Electromagnetic Interference (EMI) characteristics.

By fully utilizing available headroom, the FL77905 offers maximum power, high efficiency, power factor and low harmonic distortion. Typically, power factor is higher than 0.98 and THD is lower than 20%. The efficiency heavily depends on a LED configuration.

LED Current and Power Setting

The LED current is managed by an external current sense resistor R_{CS}. Regulation target of each channel's current sink is calculated as follows:

$$I_{LED1} = \frac{0.47}{R_{CS}}, I_{LED2} = \frac{0.86}{R_{CS}}, \text{and } I_{LED3} = \frac{0.96}{R_{CS}}. \quad (1)$$

Root-mean-square (RMS) value of the input current can be calculated using the peak regulated current, I_{LED3}, and crest factor. Since the LED current waveform is similar to the AC line voltage, the crest factor is close to the crest factor of a sine wave, $\sqrt{2}$=1.414. But the actual crest factor depends on the flattened time of the I_{LED3} and LED configuration. With FL77905, the typical crest factor is approximately 1.3. Thus, based on estimated input power, P_{IN}, the R_{CS} resistor value can be calculated as follows:

$$R_{CS} = \frac{0.96 \times V_{AC.RMS}}{1.3 \times P_{IN}} \quad (2)$$

The actual R_{CS} needs to be adjusted with respect to the LED configuration.

LED Configuration

In the LED configuration, it is required to increase the total LED forward voltage, V_F to improve efficiency. For example, compared to using 3 LEDs with V_F of 80 V (total V_F = 80 V x 3 channels = 240 V) for each LED group, using 3 LEDs with V_F of 90 V (total V_F = 90 V x 3 channels = 270 V) will improve the efficiency simply due to the higher total V_F. Each LED channel can have different V_F. For example, if a design is implemented with 144 LEDs with V_F of 3 V for 2-feet fluorescent lamp replacement, the user can assign flexible number of LEDs for LED channels such as 28s2p-34s2p-20s1p ("s" stands for LEDs in series and "p" stands for LEDs in parallel) or 27s2p-27s2p-36s1p.

Which needs to be considered is that V_F of first LED group should be higher than VIN-pin turn-on voltage, which is 20 V. If the V_F of the first LED group is configured to be lower than VIN-pin turn-on voltage, I_{LED1} will not have the correct regulation level when input voltage, V_{IN}, is just exceeds the V_F.

A good starting point for choosing a LED configuration is to have about 260 V~280 V of the total V_F for 220 V_{AC} mains and 130 V~140 V of the total V_F for 120 V_{AC}.

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Internal Shunt Regulator Output, V_{DD}

The system implemented with FL77905 does not require a bulk capacitor after bridge-rectification diodes. As a result, the V_{DD}, which supplies biasing voltage for the FL77905, has voltage ripple like the rectification voltage after the bridge diodes as shown in Figure 9.

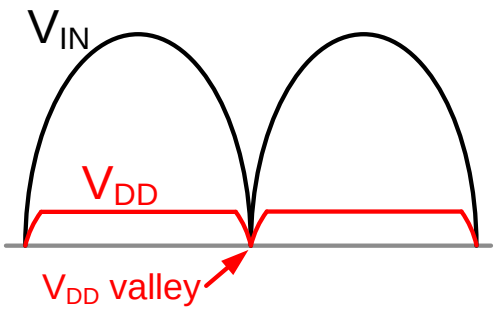


Figure 9. V_{DD} Ripple without C_{VDD}

The V_{DD} ripple can be reduced by a bypassing capacitor, C_{VDD}. If the C_{VDD} is not used, or its value is small, the V_{DD} voltage fluctuates and goes even down to 0 V. It makes the FL77905 reset, but the FL77905 automatically restarts every cycle when the AC line voltage reaches a certain level. For a much stable operation, to implement C_{VDD} is preferred. The recommended C_{VDD} value is 1 µF with 50 V of voltage rating.

Over-Temperature Protection (OTP)

The FL77905 is with over temperature protection (OTP) inherently. When the driver's junction temperature exceeds a specified threshold temperature (T_J = 170°C), the driver will shut down automatically and then recover automatically once the temperature drops lower enough than the internal threshold temperature. Without this protection, the lifetime of the FL77905 can be reduced and irreparable damage can occur when it operates above its maximum junction temperature (150°C). Good thermal management is required to achieve best performance and long life span of the FL77905.

OTP also helps to screen out non-proper thermal management during design-phase of a lighting fixture.

Analog/PWM Dimming Function

The FL77905 has its DIM pin always enabled. The DIM pin is used for analog, 0 V to 10 V, or pulse width modulation (PWM) dimming by applying a voltage signal between 0 to 5 V or PWM signals with 5-V peaks to the DIM pin.

Note that, if DIM pin is floating, there will be no LED current, since DIM pin does not source voltage by itself. If DIM-pin function is not required, use external circuit to keep DIM-pin voltage at 5 V, or use the FL77904.

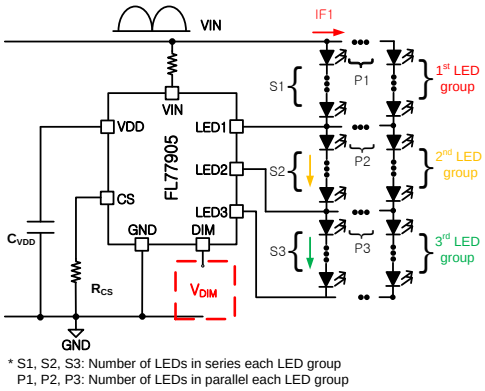


Figure 10. Analog or PWM Dimming Application

The LED channel sink and total RMS current through LEDs will be linearly adjusted with the V_{DIM} level as shown in Figure 11.

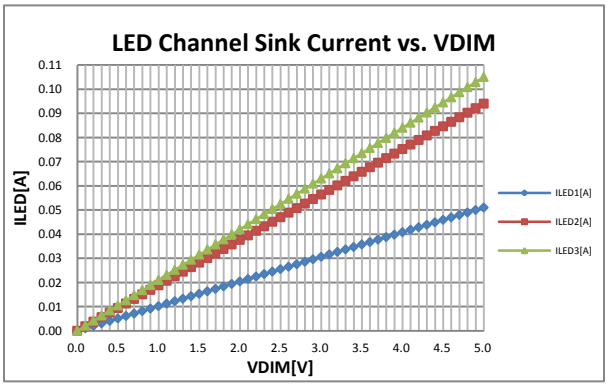
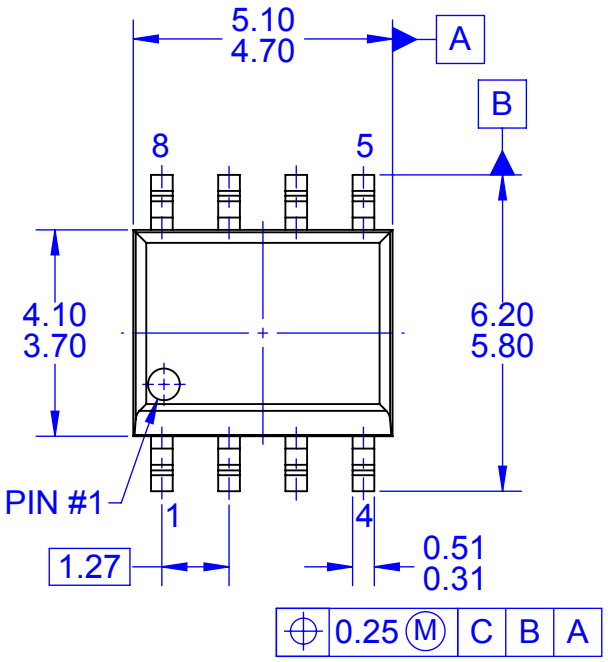
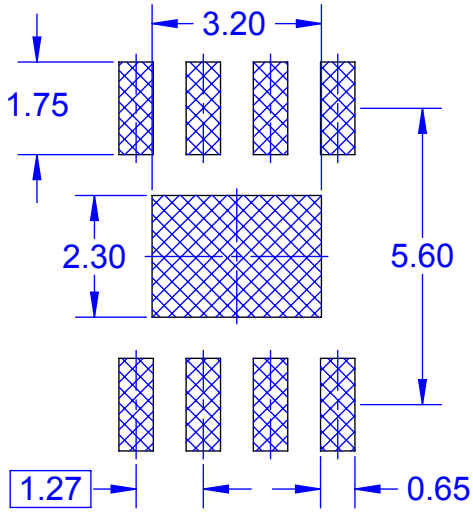


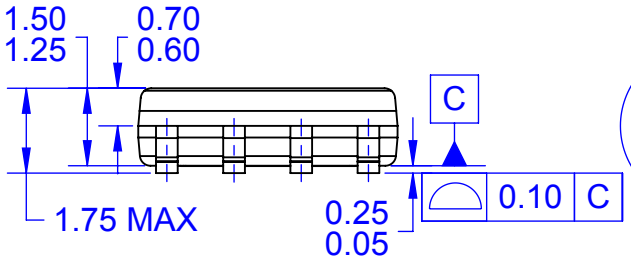
Figure 11. LED Channel Sink Current vs. VDIM (R_{CS} = 10 Ω)



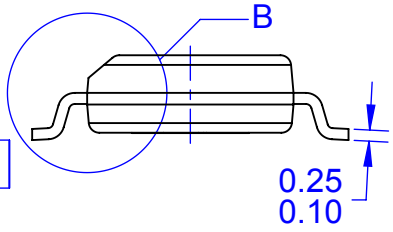
TOP VIEW



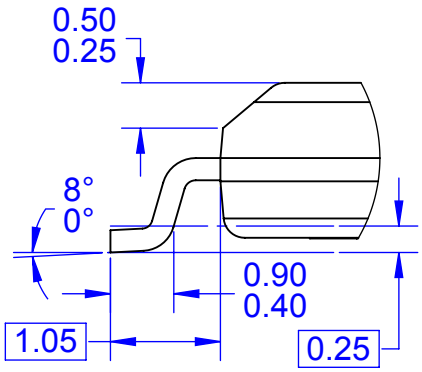
LAND PATTERN RECOMMENDATION



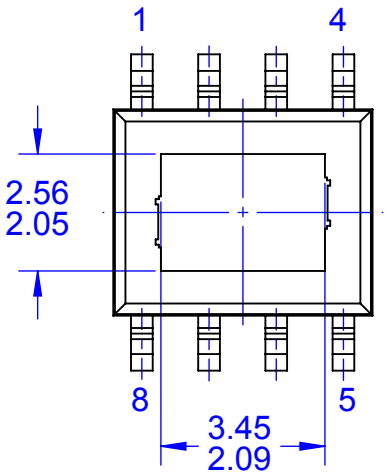
FRONT VIEW



SIDE VIEW



DETAIL B
SCALE 2:1



BOTTOM VIEW

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